

20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

-4.2A

Features

- RDS(ON), VGS@-4.5V, ID@-4.2A<52mΩ
- RDS(ON), VGS@-2.5V, ID@-3.3A<62mΩ
- RDS(ON), VGS@-1.8V, ID@-2.2A<73mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

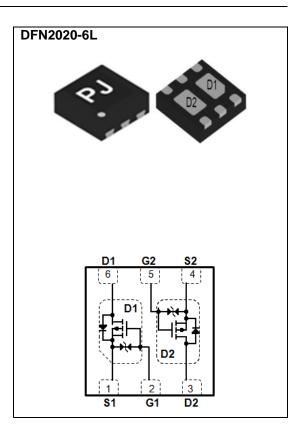
Mechanical Data

• Case: DFN2020-6L Package

Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.00032 ounces, 0.0093 grams

Marking: 815



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _G s	<u>+</u> 8	V
Continuous Drain Current		ID	-4.2	Α
Pulsed Drain Current		I _{DM}	-16.8	Α
Power Dissipation	T _a =25°C		1.5	W
	Derate above 25°C	P _D	12	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient (Note 3)		Reja	83.3	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-20	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.35	-0.55	-0.9	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V,I _D =-4.2A	-	43	52		
		V _{GS} =-2.5V,I _D =-3.3A	-	51	62	mΩ	
		V _{GS} =-1.8V,I _D =-2.2A	-	61	73		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V,V _{GS} =0V	-	-0.01	-1.0	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V,V _{DS} =0V	-	<u>+</u> 6	<u>+</u> 10	uA	
Dynamic (Note 6)							
Total Gate Charge	Q_g	\/ 40\/ L 40A	-	24	-	nC	
Gate-Source Charge	Qgs	V _{DS} =-10V, I _D =-4.2A,	-	1.5	-		
Gate-Drain Charge	Q_{gd}	VGS=-4.5V (1666 1,2)	-	2.5	-		
Input Capacitance	Ciss	101/11/01/	-	907	-	pF	
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V,	-	90	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	70	-		
Turn-On Delay Time	td _(on)	V 40V I 40A	-	45	-		
Turn-On Rise Time	tr	V _{DD} =-10V, I _D =-4.2A,	-	79	-]	
Turn-Off Delay Time	td _(off)	V_{GS} =-4.5 V , R_{G} =6 Ω (Note 1,2)	-	193	-	ns	
Turn-Off Fall Time	tf	KG=012 (1888 1,2)	-	826	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.5	А	
Diode Forward Voltage	V _{SD}	I _S =-1.0A, V _G S=0V	-	-0.66	-1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

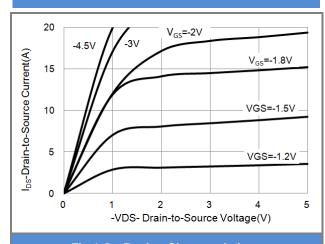


Fig.1 On-Region Characteristics

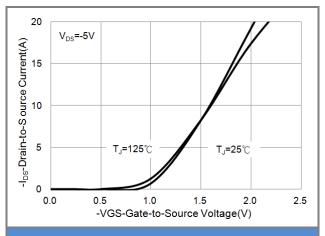


Fig.2 Transfer Characteristics

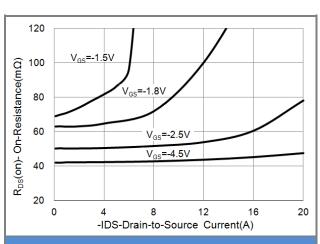


Fig.3 On-Resistance vs. Drain Current

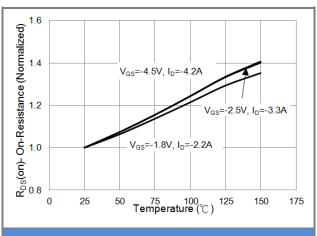


Fig.4 On-Resistance vs. Junction temperature

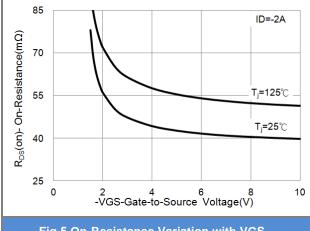
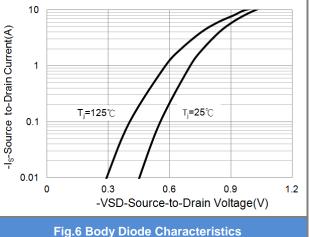


Fig.5 On-Resistance Variation with VGS.





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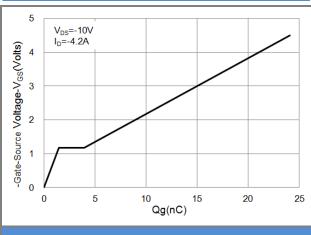


Fig.7 Gate-Charge Characteristics

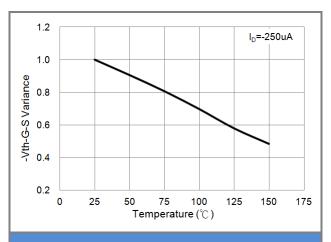


Fig.8 Threshold Voltage Variation with Temperature.

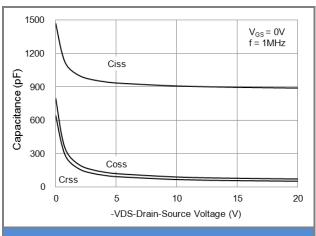


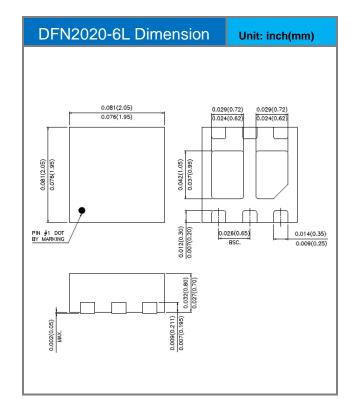
Fig.9 Capacitance vs. Drain-Source Voltage.

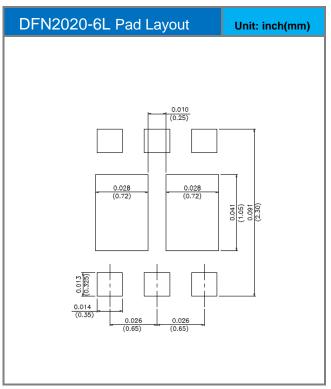


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ2815	DFN2020-6L	3K pcs / 7" reel	815

Mounting Pad Layout







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